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APPLICATION NO.	FILI	NG DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/532,283	09/532,283 03/23/2000		Koji Suzuki	1210	
23413	7590	03/25/2002			
CANTOR (,	EXAMINER		
	TN ROAD SOUTH FIELD, CT 06002			ANDUJAR, LEONARDO	
				ART UNIT	PAPER NUMBER
				2826	•
				DATE MAILED: 03/25/2002	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)					
	09/532,283	SUZUKI ET AL.					
Office Action Summary	Examiner	Art Unit					
	Leonardo Andújar	2826					
The MAILING DATE of this communication appears on the c ver sheet with the correspondenc address P ri df r Reply							
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). - Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b). Status							
1) Responsive to communication(s) filed on <u>08 J</u>	lanuary 2002 .						
2a)⊠ This action is FINAL . 2b)□ Th	is action is non-final.						
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
Disposition of Claims							
4) Claim(s) 1-22 is/are pending in the application.							
4a) Of the above claim(s) is/are withdrawn from consideration.							
5) Claim(s) is/are allowed.							
6)⊠ Claim(s) <u>1-22</u> is/are rejected.							
7) Claim(s) is/are objected to.							
8) Claim(s) are subject to restriction and/or election requirement. Application Papers							
9) The specification is objected to by the Examine	r	•					
<i>,</i> — .		miner					
10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner.							
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner. If approved, corrected drawings are required in reply to this Office action.							
12) ☐ The oath or declaration is objected to by the Examiner.							
· ·							
Priority under 35 U.S.C. §§ 119 and 120							
13)⊠ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a)⊠ All b)□ Some * c)□ None of:							
, — ,— ,—	a hava haan ragaiyad						
1. Certified copies of the priority document		ion No					
2. Certified copies of the priority document							
 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 							
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).							
 a) ☐ The translation of the foreign language provisional application has been received. 15)☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121. 							
Attachment(s)							
Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Informal	y (PTO-413) Paper No(s) Patent Application (PTO-152)					
U.S. Patent and Trademark Office							

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DETAILED ACTION

This office action is in response to a communication filed on 01/08/2002.

Acknowledgment

1. The amendment filed on 01/08/2002, paper no. 7, in response to the Office action mailed on 05/18/2001 has been entered. The present Office action is made with all the suggested amendments being fully considered. Accordingly, pending in this Office action are claims 1-22.

Priority

2. Acknowledgment is made of applicants' claim for foreign priority under 35 U.S.C. 119(a)-(d). Acknowledgment is made of applicants' claim for foreign priority based on an application filed in Japan on 03/23/1999. The certified copy of the priority document has been received.

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation

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under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

- 5. Claims 1-22 are rejected under 35 U.S.C. 103(a) as being unpatentable over applicants' admitted prior art in view of Yamauchi et al. (US 5,640,067).
- 6. Regarding claims 1 and 13, applicants' admitted prior art (e.g. fig. 1 and 2a -2b) shows an organic electroluminescence device including:
 - An organic electroluminescence element 60 and a thin film transistor 30 formed on a substrate 10;
 - An organic emissive layer 62 disposed between a first electrode (anode) 61 and a second electrode (cathode) 63;
 - > And a thin transistor active layer 43 made of polycrystalline silicon.
- 7. Also, applicants' admitted prior art teaches that the anode is made of indium tin oxide (ITO), which is a transparent conductive material. Nonetheless, applicants' admitted prior art does not disclose a refractory metal layer connecting a source region or a drain region of the thin film transistor 30 to the anode of the organic electroluminescence element. Moreover, applicants' admitted prior art does not suggest the use of a refractory metal or an alloy selected from a metal group consisting of chromium, molybdenum, tungsten and titanium. Yamauchi (e.g. fig. 1) discloses refractory metal layers (111 and 112) connecting a thin film transistor drain region 107 to a transparent electrode 109 of an organic electroluminescence element. As shown in

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figure 1, the refractory metal layers are laminated in the thickness direction of the light emitting device e.g. substrate. Moreover, Yamauchi teaches that refractory metal layers (e.g. titanium) are used to prevent the silicon atom diffusion from the drain or source region to the drain or source electrode (e.g. aluminum electrode). It would have been obvious to one of ordinary skill in the art at the time the invention was made to form a laminated refractory metal layers (in the thickness direction of the substrate) to connect the drain region to the electroluminiscence element anode of applicants' admitted prior art in order to prevent the migration of silicon atoms to the source or drain electrode as taught by Yamauchi (col. 1/lls. 24-30).

- 8. Regarding claims 2 and 14, Yamauchi discloses that the refractory metal is in direct contact with the active layer (fig. 2).
- 9. Regarding claims 3 and 15, Yamauchi discloses that the first refractory metal layer 111 is in direct contact with an active layer (105, 106 and 107). Also, Yamauchi discloses the second refractory metal layer 112 is in direct contact with the transparent electrode 109 (fig. 2).
- 10. Regarding claims 4 and 16, Yamauchi (fig. 2) shows a conductive metal layer 114 disposed between the first refractory metal 111 and the second refractory metal 112.
- 11. Regarding claims 5-7 and 17-19, applicants' admitted prior art shows an active layer 43 made of polycrystalline silicon (page 8, lines 8-10). Also, applicants' admitted prior art teaches that the anode 61 is made of indium tin oxide (page 4, lines 19-20). Yamauchi shows a conductive metal 114 made of aluminum (column 4, line 40).

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Moreover, Yamauchi teaches that the refractory metal layers are made of titanium (column 4, lines 26-67).

- 12. Regarding claims 20 and 22, applicants' admitted prior art shows that the anode is formed on a planarizing film 17.
- 13. Regarding claims 8 and 9 applicant's prior art in view of Yamauchi discloses most aspect of the instant invention (see paragraph 6-7), including a power source line 53 made of aluminum. What applicant's admitted prior art in view o Yamauchi does not disclose is a power source line having a refractory metal in direct contact with the active layer. However, Yamauchi discloses a source electrode (110 and 113) having a laminated refractory metal layer 110 (e.g. titanium) in direct contact with the active layer 105. The refractory metal layer is laminated in a thickness direction of the organic electro luminescence device. Additionally, Yamauchi discloses that conventionally refractory metals, such as chromium and titanium, are used to prevent the migration of silicon atoms to the source or drain electrode (col. 1/lls. 34-30). It would have been obvious to one of ordinary skill in the art at the time the invention was made to form the power source of applicant's prior art in view of Yamauchi having a laminated refractory metal layer (e.g. titanium) in direct contact to the active layer in order to prevent the migration of silicon atoms to the electrode as taught by Yamauchi.
- 14. Regarding claim 10, Yamauchi discloses a first refractory metal layer 111, which is in direct contact with an active layer. Also, Yamauchi discloses a second refractory metal layer 112, which is in direct contact with the transparent electrode of the organic

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electroluminescence element (fig. 2). Additionally, a conductive metals layer 114 is disposed between the first refractory metal 111 and the second refractory metal 112.

- 15. Regarding claim 11, applicants' admitted prior art shows an active layer 43 made of polycrystalline silicon (page 8, lines 8-10) and the anode 61 made of indium tin oxide (page 4, lines 19-20).
- 16. Regarding claim 12, applicants' admitted prior art shows (fig. 1, 2A and 2B) a pixel has a switching thin film transistor 30 having a gate connected to gate line, one of the source and drain in the active layer made of semiconductor material and connected to a data line. The other source or and drain is connected to a gate of a thin film transistor 40 to control the flow of current supplied from the power source line 53 to the organic electroluminescence element. Moreover, the active layer of the switching thin film transistor making contact with the data line via a metal. Yamauchi discloses a refractory metal to make contact with a data line.
- 17. Regarding claim 21, applicants' admitted prior art shows that the anode is formed on a planarizing film 17.

Response to Arguments

18. In response to applicants' arguments against the references individually, one cannot show nonobviousness by attacking references individually where the rejections are based on combinations of references. See *In re Keller*, 642 F.2d 413, 208 USPQ 871 (CCPA 1981); *In re Merck & Co.*, 800 F.2d 1091, 231 USPQ 375 (Fed. Cir. 1986). In any case, Examiner respectfully disagrees with applicants' argument that Yamauchi does not teach a refractory metal layer that is laminated in a thickness direction of the

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device substrate (new limitation). By definition, a laminated structure is composed of layers of firmly united material. Moreover, Yamauchi (e.g. fig. 1) noticeably shows a structure composed of layers (111,112,114) of firmly united material. Yamauchi teaches that the refractory metal layers are formed in a thickness direction of the substrate or/and light-emitting device (i.e. organic electroluminescence device). Furthermore, Yamauchi shows that the refractory metal layers (111 and 112) are formed at the source or drain electrode ends (114) to connect the transparent electrode and source or drain regions. Therefore, Yamauchi teaching suggests that the refractive layers have to be formed at the analogous contact locations of applicants' admitted prior art electrode in order to prevent the electrode of being contaminated with silicon. The analogous contact locations are the top and bottom regions of applicants' admitted prior art source or drain electrode. The adverse effects of the silicon diffusion are well known in the art. In conclusion, Yamauchi teaching is used to demonstrate that one having ordinary skill in the art at the time of the invention was made would use refractory metal layers at the electrode contact regions in order to prevent the silicon diffusion. Referring to figures 1, 3c and 3d, Yamauchi evidently shows that the refractory metal layers (111 and 112) are laminated in a substrate thickness direction, see for example the regions contacting the transparent electrode 109 and the drain region 107. applicants' admitted prior art in view of Yamauchi teaches all the limitations of amended claims (1, 8 and 13). In response to applicants' argument that Yamauchi is allegedly moot with regards to the effects as obtained by Applicants' invention, the fact that applicant has recognized another advantage which would flow naturally from following

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the suggestion of the admitted prior art cannot be the basis for patentability when the differences would otherwise be obvious. See *Ex parte Obiaya*, 227 USPQ 58, 60 (Bd. Pat. App. & Inter. 1985).

Conclusion

- THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time 19. policy as set forth in 37 CFR 1.136(a). A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action. Papers related to this application may be submitted directly to Art Unit 2826 by facsimile transmission. Papers should be faxed to Art Unit 2826 via the Art Unit 2826 Fax Center located in Crystal Plaza 4, room 4C23. The faxing of such papers must conform to the notice published in the Official Gazette, 1096 OG 30 (15 November 1989). The Art Unit 2826 Fax Center number is (703) 308-7722 or -7724. The Art Unit 2826 Fax Center is to be used only for papers related to Art Unit 2814 applications.
- 20. Any inquiry concerning this communication or earlier communications from the examiner should be directed to **Leonardo Andújar** at **(703) 308-0080** and between the hours of 9:00 AM to 5:00 PM (Eastern Standard Time) Monday through Friday or by e-

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mail via Leonardo. Andujar@uspto.gov. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan Flynn, can be reached on (703) 308-6601. Any inquiry of a general nature or relating to the status of this application should be directed to the **Group 2800 Receptionist** at **(703) 305-3900**.

21. The following list is the Examiner's field of search for the present Office Action:

Field of Search	
U.S. Class / Subclass (es): 257/40, 501; 438/7	03/2002
Other Documentation:	
Electronic Database(s): East (USPAT, US PGPUB, JPO, EPO, Derwent, IBM TDB)	03/2002

Leonardo Andújar Patent Examiner Art Unit 2826 LA 3/18/02

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ⁱ Merriam-Webster's Collegiate Dictionary, Merriam-Webster Inc., 10th edition, page 653.